

MAY 17 2004

OFFICIAL
PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of:

Hiroyuki Nitta et al.

Serial No.: 09/883,210

Filed: June 19, 2001

For: Semiconductor Device Having A
Wiring Layer Of Damascene
Structure And Method For
Manufacturing The Same

Group Art Unit: 2815

Examiner: J. Nguyen

Atty. Dkt. No. 01701.00086

RECEIVED

JUN 25 2004

OFFICE OF PETITIONS

This paper of 1 page is being faxed to 703 308 7722
on April 19, 2002.*Christopher R. Glembocki*
Christopher R. Glembocki
Reg. No. 38,800#12
ElectionJ. Majumder
7/6/04**RESPONSE TO ELECTION REQUIREMENT**Assistant Commissioner of Patents
Washington, D.C. 20231

Sir:

This paper is responsive to the Restriction Requirement mailed February 7, 2002, and to the Holding of Applicants response as non-responsive of March 22, 2002. This paper is filed within one month of the March 22, 2002, communication.

Applicants hereby elect Species V, relating to Figures 6A-6E, without traverse. Claims 1-4 and 10-15 correspond to Species V.

Applicant reserves the right to file a divisional application directed to the non-elected invention. A preliminary amendment is filed herewith under separate cover. Please charge any fee associated with the filing of this paper to our Deposit Account No. 19-0733.

Respectfully submitted,

By: *Joseph M. Potenza*

Joseph M. Potenza

Registration No. 28,175 *#38800*BANNER & WITCOFF, LTD.
1001 G Street, N.W., 11th Floor
Washington, D.C. 20001
(202) 508-9100
Dated: April 19, 2002

MAY 17 2004

OFFICIAL

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of:

Hiroyuki Nitta et al.

Serial No.: 09/883,210

Filed: June 19, 2001

For: Semiconductor Device Having A
Wiring Layer Of Damascene
Structure And Method For
Manufacturing The Same

Group Art Unit: 2815

Examiner: J. Nguyen

Atty. Dkt. No. 01701.00086

RECEIVED

JUN 25 2004

OFFICE OF PETITIONS

This paper of 3 pages is being faxed to 703 308 7722
on April 19, 2002.*Christopher R. Glembocki*
Christopher R. Glembocki
Reg. No. 38,800AMENDMENTAssistant Commissioner of Patents
Washington, D.C. 20231

Sir:

Please amend the application as follows:

In the Claims:

Please amend claim 4 as follows:

4. (Amended) The semiconductor device according to claim 1, further
comprising:a second insulation film formed above the space region, the second insulation film being
different from the first insulation film; anda third insulation film formed on a sidewall of the groove section, the third insulation film
being different from the first and second insulation films.

04/19/02 17:33 FAX

*** TX REPORT ***

MAY 17 2004

OFFICIAL

TRANSMISSION OK

TX/RX NO	1728
CONNECTION TEL	701*00086#7033087722
SUBADDRESS	
CONNECTION ID	
ST. TIME	04/19 17:32
USAGE T	00:43
PGS. SENT	
RESULT	OK

OK

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Application of:

Hiroyuki Nitta et al.

Serial No.: 09/883,210

Filed: June 19, 2001

For: Semiconductor Device Having A
Wiring Layer Of Damascene
Structure And Method For
Manufacturing The Same

Group Art Unit: 2815

Examiner: J. Nguyen

Atty. Dkt. No. 01701.00086

This paper of 3 pages is being faxed to 703 308 7722
on April 19, 2002.*Christopher R. Glembocki*
Christopher R. Glembocki
Reg. No. 38,800AMENDMENTAssistant Commissioner of Patents
Washington, D.C. 20231

Sir:

Please amend the application as follows:

In the Claims:

Please amend claim 4 as follows:

4. (Amended) The semiconductor device according to claim 1, further
comprising:a second insulation film formed above the space region, the second insulation film being
different from the first insulation film; and